

WS3A016120K

Silicon Carbide Schottky Diode

| V _{RRM} | = | 1200 | V |
|---|---|------|------|
| I _F (T _C ≤135°C) | = | 24 | A** |
| Q _C | = | 46 | nC** |

Features

- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- Positive Temperature Coefficient on V_F
- Temperature-independent Switching
- 175°C Operating Junction Temperature

Benefits

- Replace Bipolar with Unipolar Device
- Reduction of Heat Sink Size
- Parallel Devices Without Thermal Runaway
- Essentially No Switching Losses

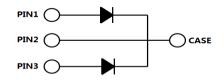
Applications

- Switch Mode Power Supplies
- Power Factor Correction
- Motor drive, PV Inverter, Wind Power Station

Package



TO-247-3



| Part Number | Package | Marking |
|-------------|----------|-------------|
| WS3A016120K | TO-247-3 | WS3A016120K |

Maximum Ratings

| Symbol | Parameter | Value | Unit | Test Conditions | Note |
|-----------------------------------|--|--------------------------|------|---|-------|
| V_{RRM} | Repetitive Peak Reverse Voltage | 1200 | ٧ | T _C = 25°C | |
| V_{RSM} | Surge Peak Reverse Voltage | 1200 | ٧ | T _C = 25°C | |
| V_R | DC Blocking Voltage | 1200 | ٧ | $T_C = 25^{\circ}C$ | |
| l _F | Forward Current (Per leg/Device) | 24.5/49 12/24 8/16 | Α | $T_C \le 25^{\circ}C$ $T_C \le 135^{\circ}C$ $T_C \le 155^{\circ}C$ | |
| I _{FSM} | Non-Repetitive Forward Surge Current | 80* | Α | $T_C = 25^{\circ}C$, $t_p = 8.3$ ms, Half Sine Wave | |
| P _{tot} | Power Dissipation (Per leg/Device) | 140/ 280 | W | T _C = 25°C | Fig.3 |
| T _C | Maximum Case Temperature | 155 | Ŋ | | |
| T _J , T _{STG} | Operating Junction and Storage Temperature | -55 to 175 | °C | | |
| | TO-247 Mounting Torque | 1 | Nm | M3 Screw | |

^{*}Per Leg, **Per Device



Electrical Characteristics (Per Leg)

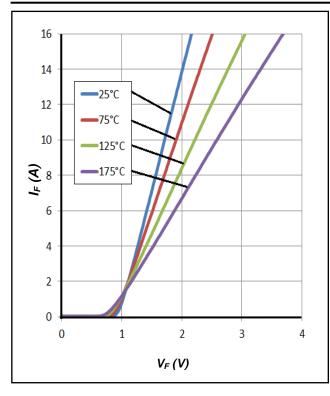
| Symbol | Parameter | Тур. | Max. | Unit | Test Conditions | Note | |
|----------------|-------------------------|----------------------------|------|------|--|--------|--|
| V | Forward Voltage | 1.55 | 1.8 | V | I _F = 8A, T _J = 25°C | Fig 1 | |
| V _F | Forward Voltage | 2.2 | 2.5 | ٧ | I _F = 8A, T _J = 175°C | Fig.1 | |
| | December Comment | 1 | 20 | ^ | V _R = 1200V, T _J = 25°C | Ε: - 0 | |
| I _R | Reverse Current | 8 | 100 | μA | V _R = 1200V, T _J = 175°C | Fig.2 | |
| | | 520 | | | $V_R = 0V, T_J = 25^{\circ}C, f = 1MHz$ | | |
| С | Total Capacitance | 38 | / | pF | $V_R = 400V, T_J = 25^{\circ}C, f = 1MHz$ | Fig.5 | |
| | | 30 | | | $V_R = 800V, T_J = 25^{\circ}C, f = 1MHz$ | | |
| Qc | Total Capacitive Charge | | | | $V_R = 800V, I_F = 8A$ | | |
| | | Total Capacitive Charge 23 | / | nC | di/dt = 200A/μs, Τ _J = 25°C | Fig.4 | |

Thermal Characteristics

| Symbol | Parameter | Тур. | Unit | Note |
|---|---|------------------|------|-------|
| R _{BJC} Thermal Resistance from Junction to Case | | 1.07* 0.535** | °C/W | Fig.6 |
| $R_{\theta JA}$ | Thermal Resistance from Junction to Ambient | 80 | °C/W | |
| T _{sold} Soldering Temperature | | 260 | °C | |

^{*}Per Leg, **Per Device

Typical Performance (Per Leg)



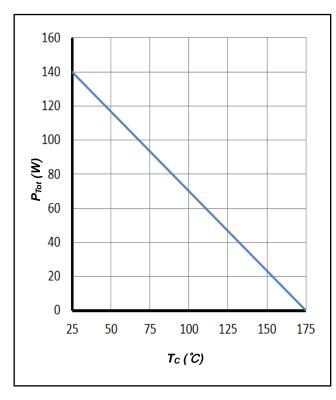
100 80 60 75°C 125°C 125°C 175°C 175°C 120 1500 V_R (V)

Figure 1. Forward Characteristics

Figure 2. Reverse Characteristics

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Typical Performance (Per Leg)



25 20 15 0 0 0 300 600 900 1200 V_R (V)

Figure 3. Power Derating

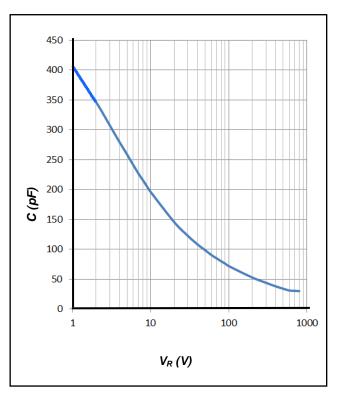


Figure 5. Total Capacitance vs. Reverse Voltage

Figure 4. Total Capacitive Charge vs. Reverse Voltage

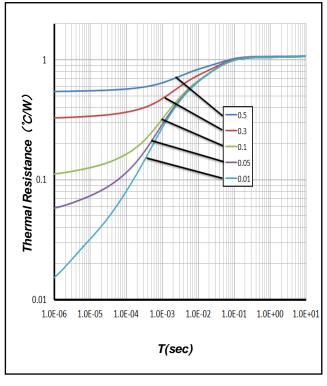
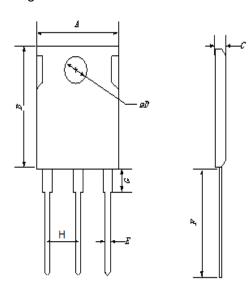


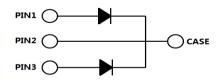
Figure 6. Transient Thermal Impedance

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Package Dimensions

Package TO-247-3

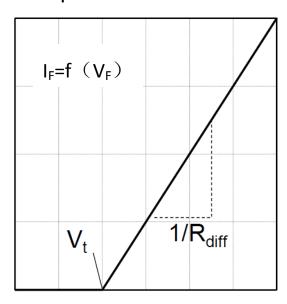




| Symbol | Min. (mm) | Typ. (mm) | Max. (mm) |
|--------|-----------|-----------|-----------|
| Α | 14.18 | 15.75 | 17.33 |
| В | 18.45 | 20.5 | 22.55 |
| С | 4.50 | 5.00 | 5.50 |
| D | 3.15 | 3.50 | 3.85 |
| Ш | 1.08 | 1.20 | 1.32 |
| F | 18.27 | 20.30 | 22.33 |
| G | 4.21 | 4.68 | 5.15 |
| Н | 4.91 | 5.46 | 6.01 |

Simplified Diode Model (Per Leg)

Equivalent IV Curve for Model



Mathematical Equation

$$V_F = V_t + I_F \times R_{diff}$$

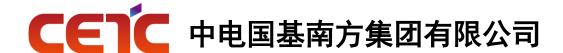
$$\begin{split} V_t &= -0.0025 \textbf{x} T_j + 0.99 \; [V] \\ R_{diff} &= 1.73 \textbf{x} 10^{-6} \textbf{x} T_j^2 + 3.64 \textbf{x} 10^{-4} \textbf{x} T_j + 0.066 \; [\Omega] \end{split}$$

Note:

 $\label{eq:Tj} \mbox{Tj = Diode Junction Temperature In Degrees Celsius,} \\ \mbox{valid from } 25\mbox{°C to } 175\mbox{°C}$

I_F= Forward Current

Less than 16A



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